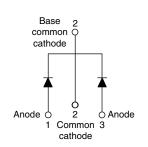


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# Schottky Rectifier, 2 x 15 A

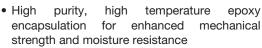




PRODUCT SUMMARY					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 15 A				
$V_R$	35 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	See Electrical table				
I <sub>RM</sub> max.	40 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	16 mJ				

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform (per device)	30	А			
V <sub>RRM</sub>		35/45	V			
I <sub>FRM</sub>	T <sub>C</sub> = 130 °C (per leg)	30	^			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	A			
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.73	V			
TJ	Range	- 65 to 150	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBR2535CTPbF	VS-MBR2535CT-N3	VS-MBR2545CTPbF	VS-MBR2545CT-N3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	\ \ <u>\</u>		
Maximum working peak reverse voltage	V <sub>RWM</sub>	35	35	45	45	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average per leg		T <sub>C</sub> = 130 °C, rated V <sub>R</sub>		15		
forward current per device	I <sub>F(AV)</sub>			30		
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 130 °C		30		
Non-repetitive peak surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	Α	
, ,	. 5	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150		
Non-repetitive avalanche energy per le	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 8  \text{mH}$		16	mJ	
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by $T_J$ maximum $V_A = 1.5 \text{ x } V_R$ typical		2	А	

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	30 A	T <sub>J</sub> = 25 °C	0.82	V	
	VFM (")	30 A	T <sub>J</sub> = 125 °C	0.73	V	
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Dated DC valtage	0.2	mA	
	IRM (*)	T <sub>J</sub> = 125 °C	Rated DC voltage	40		
Threshold voltage	V <sub>F(TO)</sub>	T. T. vicinia		0.355	٧	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		12.3	mΩ	
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz) 25 °C		700	pF	
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8.0	nΗ	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

### Note

 $<sup>^{(1)}~</sup>$  Pulse width < 300  $\mu s,~duty~cycle < 2~\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		- 65 to 150	°C		
Maximum storage temperature range	T <sub>Stg</sub>		- 65 to 175	10		
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.5	°C/W		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased		J, W		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm		
maximum		Non-lubricateu tirreaus	12 (10)	(lbf · in)		
Marking device		Case style TO-220AB	MBR2535CT			
ivial king device		Case style 10-220AD	MBR2545CT			

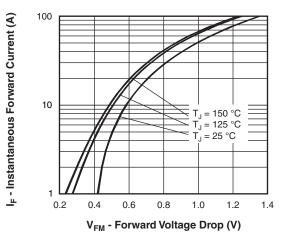


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

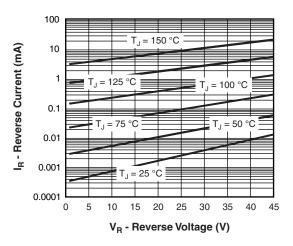


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

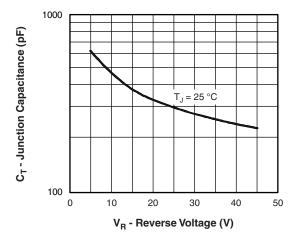


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

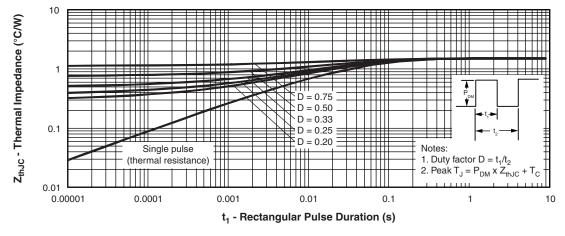


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

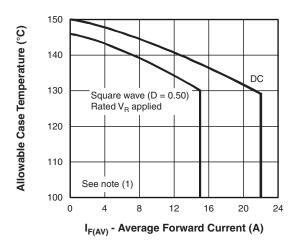


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

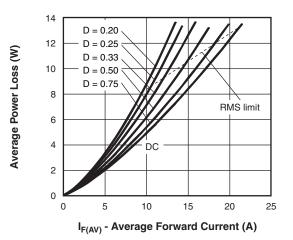


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

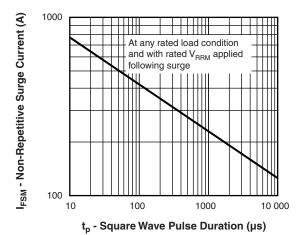


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

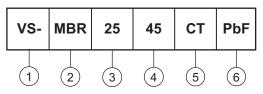
### Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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## **ORDERING INFORMATION TABLE**





- Vishay Semiconductors product

2 - Schottky MBR series

Current rating (30 A)

35 = 35 V 45 = 45 V

5 - CT = Essential part number

Environmental digit

PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBR2535CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2535CT-N3	50	1000	Antistatic plastic tube				
VS-MBR2545CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2545CT-N3	50	1000	Antistatic plastic tube				

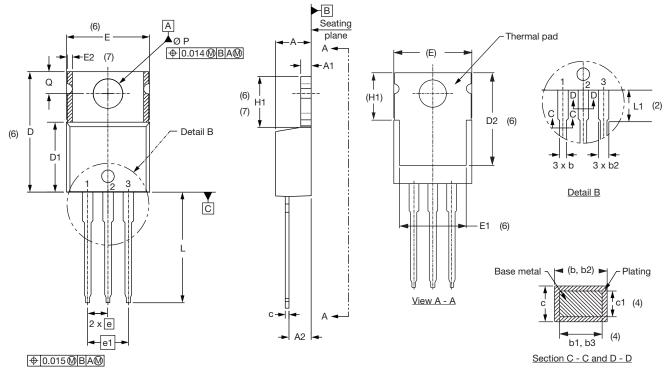
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dout moulting information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



## Vishay Semiconductors

## **TO-220AB**

### **DIMENSIONS** in millimeters and inches



## Lead assignments



- Anode/open
  Cathode
- 3. Anode

**Diodes** 

### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL		MILLIN	IETERS	INC	HES	NOTES
STIVI	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е		10.11	10.51	0.398	0.414	3, 6
Е	1	6.86	8.89	0.270	0.350	6
E	2	-	0.76	-	0.030	7
e	)	2.41	2.67	0.095	0.105	
e	1	4.88	5.28	0.192	0.208	
Н	1	6.09	6.48	0.240	0.255	6, 7
L	-	13.52	14.02	0.532	0.552	
L	1	3.32	3.82	0.131	0.150	2
Ø	Р	3.54	3.73	0.139	0.147	
C	)	2.60	3.00	0.102	0.118	
$\epsilon$	)	90° to 93°		90° t	o 93°	

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$  Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



## **Legal Disclaimer Notice**

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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